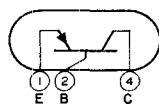


TRANSISTOR



Germanium p-n-p type used in large-signal audio-frequency amplifier applications. It is used in class B push-pull power-output stages of battery-operated portable radio receivers and audio amplifiers and in class A high-gain driver stages. JEDEC No. TO-40 package; outline 15, Outlines Section.

2N109

MAXIMUM RATINGS

COLLECTOR-TO-BASE VOLTAGE (with emitter open).....	-25 max	volts
COLLECTOR-TO-EMITTER VOLTAGE.....	-25 max	volts
EMITTER-TO-BASE VOLTAGE (with collector open).....	-12 max	volts
COLLECTOR CURRENT.....	-70 max	ma
EMITTER CURRENT.....	70 max	ma
TRANSISTOR DISSIPATION:		
At ambient temperatures up to 25°C.....	150 max	mW
At ambient temperature of 55°C.....	50 max	mW
At ambient temperature of 71°C.....	20 max	mW
AMBIENT-TEMPERATURE RANGE:		
Operating.....	-65 to 71	°C
Storage.....	-65 to 85	°C

CHARACTERISTICS

Collector-Cutoff Current (with collector-to-base volts = -25 and emitter current = 0).....	-14	μa
Emitter-Cutoff Current (with emitter-to-base volts = -12 and collector current = 0).....	-14	μa

In Common-Emitter Circuit

DC Forward Current-Transfer Ratio (with collector-to-emitter volts = -1 and collector ma = -50).....	75	
--	----	--

TYPICAL OPERATION IN CLASS B PUSH-PULL AF AMPLIFIER CIRCUIT

Values are for two transistors except as noted

DC Collector-to-Emitter Supply Voltage.....	-4.5	-9	volts
DC Base-to-Emitter Voltage.....	-0.15	-0.15	volt
Peak Collector Current (approx.) per transistor.....	-35	-40	ma
Maximum-Signal DC Collector Current (approx.) per transistor.....	-11.5	-13	ma
Zero-Signal DC Collector Current (approx.) per transistor.....	-2	-2	ma
Signal-Source Impedance per base.....	375	375	ohms
Load Impedance per collector.....	100	200	ohms
Signal Frequency.....	1	1	kc
Circuit Efficiency at maximum rated output.....	60	69	per cent
Power Gain.....	30	33	db
Total Harmonic Distortion.....	10 max	10 max	per cent
Maximum-Signal Power Output.....	75	160	mW

